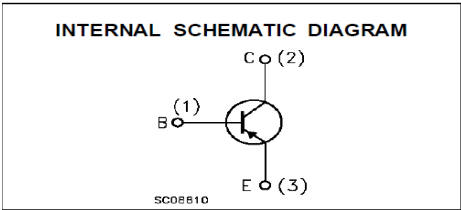
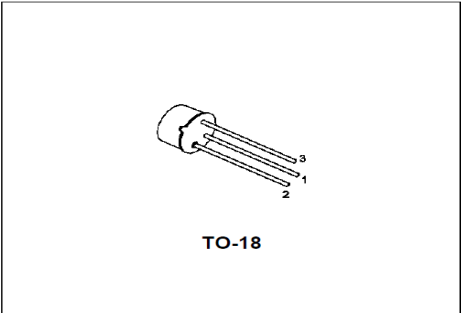


BC107 PLOT hFE vs IC:

LOW NOISE GENERAL PURPOSE AUDIO AMPLIFIERS

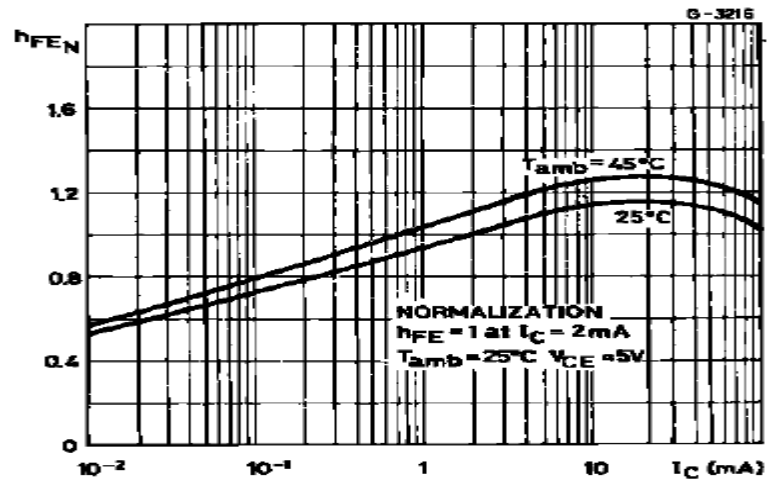
**DESCRIPTION**  
The BC107 and BC108 are silicon planar epitaxial NPN transistors in TO-18 metal case. They are suitable for use in driver stages, low noise input stages and signal processing circuits of television receivers. The PNP complement for BC107 is BC177.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit
		BC107	BC108	
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	50	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)	45	20	V
V <sub>EB0</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	6	5	V
I <sub>C</sub>	Collector Current	100		mA
P <sub>tot</sub>	Total Dissipation at T <sub>amb</sub> ≤ 25 °C at T <sub>case</sub> ≤ 25 °C	0.3 0.75		W W
T <sub>stg</sub>	Storage Temperature	-55 to 175		°C
T <sub>j</sub>	Max. Operating Junction Temperature	175		°C

## DC Normalized Current Gain.



%BC107-hFE plot vs IC

hFE=[40 49 56 66 74 80 85 90 94 104 105 104 102 90];%beta

IC=[.97\*10^-3 10\*10^-3 20\*10^-3 30\*10^-3 40\*10^-3 50\*10^-3 60\*10^-3 70\*10^-3  
80\*10^-3 90\*10^-3 100\*10^-3 110\*10^-3 125\*10^-3 160\*10^-3 ];%A

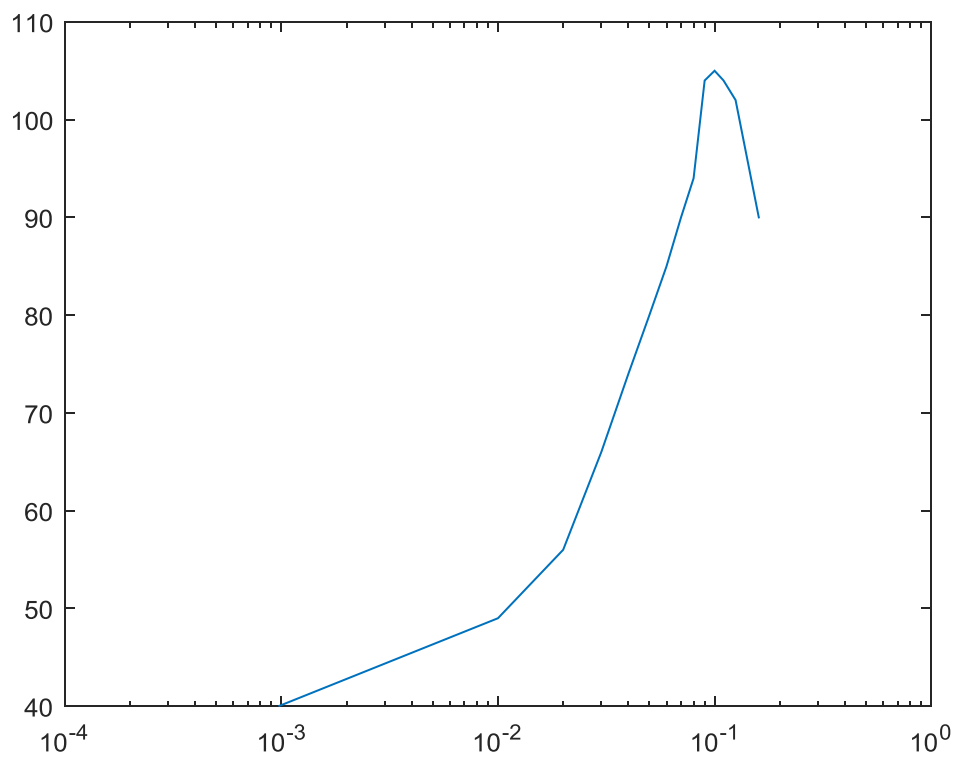
semilogx(IC,hFE);

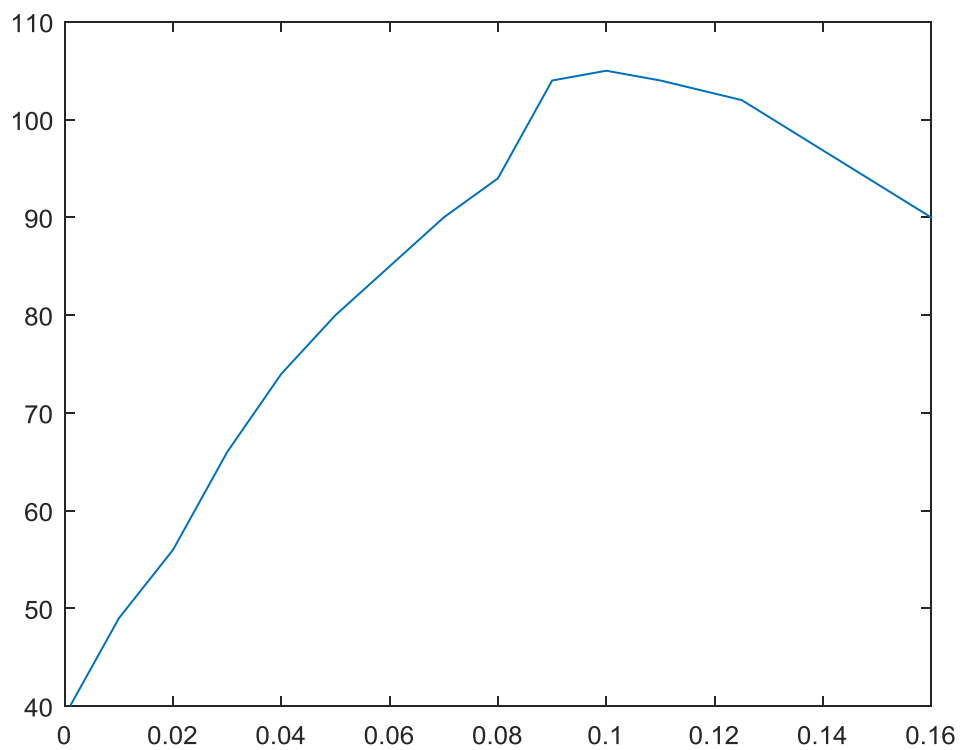
figure;

plot(IC,hFE,'ro');

figure;

plot(IC,hFE);





The end